

Advance Data

## High Power Sonic FRD Type E4000TC25C

### Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
$V_{RRM}$	Repetitive peak reverse voltage, (note 1)	2500	V
$V_{RSM}$	Non-repetitive peak reverse voltage, (note 1)	2600	V
$V_{R(d.c.)}$	Maximum reverse d.c. voltage (note 1)	1500	V

	OTHER RATINGS (note 6)	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Mean forward current, $T_{sink}=55^{\circ}C$ , (note 2)	4080	A
$I_{F(AV)M}$	Mean forward current. $T_{sink}=100^{\circ}C$ , (note 2)	2630	A
$I_{F(AV)M}$	Mean forward current. $T_{sink}=100^{\circ}C$ , (note 3)	1572	A
$I_{F(RMS)}$	Nominal RMS forward current, $T_{sink}=25^{\circ}C$ , (note 2)	7662	A
$I_{F(d.c.)}$	D.C. forward current, $T_{sink}=25^{\circ}C$ , (note 4)	6557	A
$I_{FSM}$	Peak non-repetitive surge $t_p=10ms$ , $V_{RM}=60\%V_{RRM}$ , (note 5)	50	kA
$I_{FSM2}$	Peak non-repetitive surge $t_p=10ms$ , $V_{RM}\leq 10V$ , (note 5)	55	kA
$I^2t$	$I^2t$ capacity for fusing $t_p=10ms$ , $V_{RM}=60\%V_{RRM}$ , (note 5)	$12.5\times 10^{-6}$	$A^2s$
$I^2t$	$I^2t$ capacity for fusing $t_p=10ms$ , $V_{RM}\leq 10V$ , (note 5)	$15.1\times 10^{-6}$	$A^2s$
$P_{rr}$	Maximum non-repetitive peak reverse recovery power, (note 7)	15	MW
$T_{j op}$	Operating temperature range	-40 to +150	$^{\circ}C$
$T_{stg}$	Storage temperature range	-40 to +150	$^{\circ}C$

Notes:-

- De-rating factor of 0.13% per  $^{\circ}C$  is applicable for  $T_j$  below  $25^{\circ}C$ .
- Double side cooled, single phase; 50Hz,  $180^{\circ}$  half-sinewave.
- Single side cooled, single phase; 50Hz,  $180^{\circ}$  half-sinewave.
- Double side cooled.
- Half-sinewave,  $150^{\circ}C$   $T_j$  initial.
- Current ( $I_F$ ) ratings have been calculated using  $V_{T0}$  and  $r_T$  (see page 2)
- $T_j=T_{jop}$ ,  $I_F=2250A$ ,  $di/dt=2500A/\mu s$ ,  $V_r=1250V$  and  $L_s=200nH$ . Test circuit and sample waveform are shown in diagram 1. IGBT type T2250AB25E used as switch.

**Characteristics**

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
$V_{FM}$	Maximum peak forward voltage	-	1.87	2.0	$I_{FM}=4000A$	V
		-	-	2.66	$I_{FM}=8000A$	
$V_{T0}$	Threshold voltage	-	-	1.406	Current range 4080 A - 12240A (Note 2)	V
$r_T$	Slope resistance	-	-	0.149		m $\Omega$
$V_{T01}$	Threshold voltage	-	-	1.4	Current range 4000A - 12000A	V
$r_{T1}$	Slope resistance	-	-	0.15		m $\Omega$
$V_{FRM}$	Maximum forward recovery voltage	-	-	50	$di/dt = 3000A/\mu s$	V
		-	-	25	$di/dt = 3000A/\mu s, T_j=25^\circ C$	
$I_{RRM}$	Peak reverse current	-	-	100	Rated $V_{RRM}$	mA
		-	-	10	Rated $V_{RRM}, T_j=25^\circ C$	
$Q_{rr}$	Recovered charge	-	6700	7400	$I_{FM}=4000A, t_p=1ms, di/dt=3500A/\mu s, V_f=1250V, 50%$ and $L_s=200nH$ . IGBT type T2250AB25E used as switch. (note 3)	$\mu C$
$Q_{ra}$	Recovered charge, 50% Chord	-	3100	-		$\mu C$
$I_{rm}$	Reverse recovery current	-	2480	2700		A
$t_{rr}$	Reverse recovery time, 50% Chord	-	2.5	-		$\mu s$
$R_{thJK}$	Thermal resistance, junction to heatsink	-	-	0.008	Double side cooled	K/W
		-	-	0.016	Single side cooled	K/W
F	Mounting force	60	-	75	(Note 4)	kN
$W_t$	Weight	-	1.23	-		kg

## Notes:-

- 1) Unless otherwise indicated  $T_j=150^\circ C$ .
- 2)  $V_{T0}$  and  $r_T$  were used to calculate the current ratings illustrated on page one.
- 3) Figures 3-7 were compiled using these conditions. Test circuit and sample waveform are shown in diagram 1.
- 4) For clamp forces outside these limits, please consult factory.

**Additional information on Ratings and Characteristics**

**1.0 De-rating Factor**

A blocking voltage de-rating factor of 0.13% per °C is applicable to this device for T<sub>j</sub> below 25°C.

**2.0 ABCD Constants**

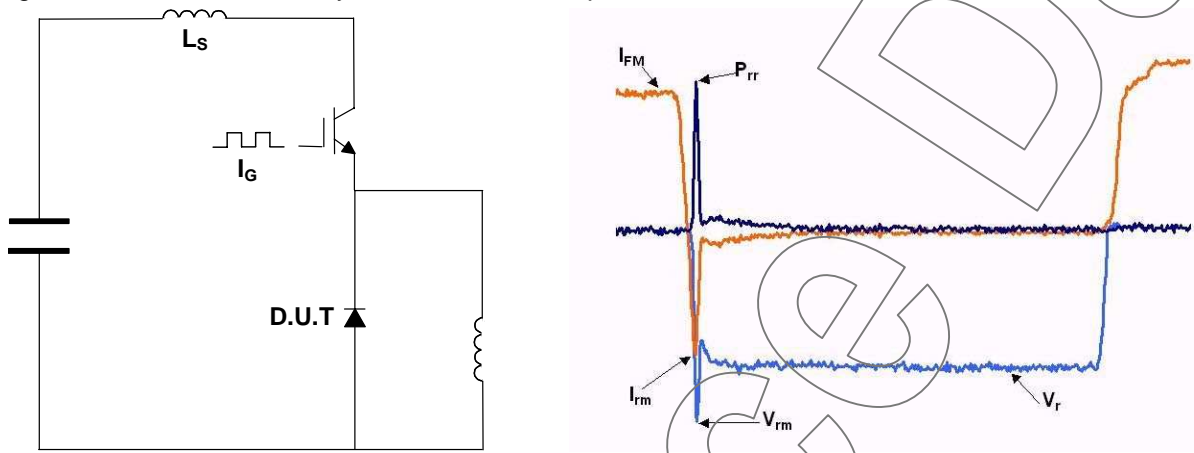
These constants (applicable only over current range of V<sub>F</sub> characteristic in Figure 1) are the coefficients of the expression for the forward characteristic given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

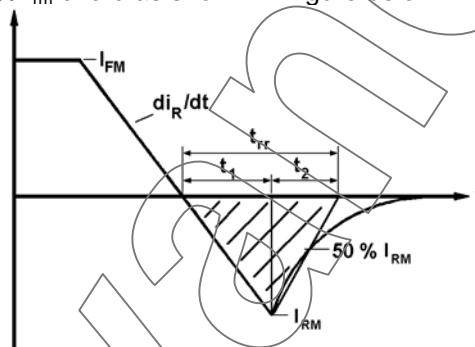
where I<sub>F</sub> = instantaneous forward current.

**3.0 Reverse recovery ratings**

Diagram 1 – Reverse Recovery test circuit and sample waveform



(i) Q<sub>ra</sub> is based on 50% I<sub>rm</sub> chord as shown in Figure below.



(ii) Q<sub>rr</sub> is based on a 150µs integration time.

i.e.

$$Q_{rr} = \int_0^{150\mu s} i_{rr} \cdot dt$$

(iii)

$$K \text{ Factor} = \frac{t_1}{t_2}$$

#### 4.0 Reverse Recovery Loss

The following procedure is recommended for use where it is necessary to include reverse recovery loss.

From waveforms of recovery current obtained from a high frequency shunt (see Note 1) and reverse voltage present during recovery, an instantaneous reverse recovery loss waveform must be constructed. Let the area under this waveform be E joules per pulse. A new sink temperature can then be evaluated from:

$$T_{SINK} = T_{J(MAX)} - E \cdot [k + f \cdot R_{th(J-Hs)}]$$

Where k = 0.2314 (°C/W)/s

E = Area under reverse loss waveform per pulse in joules (W.s.)

f = Rated frequency in Hz at the original sink temperature.

$R_{th(J-Hs)}$  = d.c. thermal resistance (°C/W)

The total dissipation is now given by:

$$W_{(tot)} = W_{(original)} + E \cdot f$$

##### NOTE 1 - Reverse Recovery Loss by Measurement

This device has a low reverse recovered charge and peak reverse recovery current. When measuring the charge, care must be taken to ensure that:

(a) AC coupled devices such as current transformers are not affected by prior passage of high amplitude forward current.

(b) A suitable, polarised, clipping circuit must be connected to the input of the measuring oscilloscope to avoid overloading the internal amplifiers by the relatively high amplitude forward current signal.

(c) Measurement of reverse recovery waveform should be carried out with an appropriate critically damped snubber, connected across diode anode to cathode. The formula used for the calculation of this snubber is shown below:

$$R^2 = 4 \cdot \frac{V_r}{C_s \cdot di/dt}$$

Where:  $V_r$  = Commutating source voltage

$C_s$  = Snubber capacitance

R = Snubber resistance

#### 5.0 Computer Modelling Parameters

##### 5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T}$$

Where  $V_{T0} = 1.406V$ ,  $r_T = 0.149m\Omega$

$ff$  = form factor (normally unity for fast diode applications)

$$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j(MAX)} - T_K$$

## 5.2 Calculation of $V_F$ using ABCD Coefficients

The forward characteristic  $I_F$  Vs  $V_F$ , on page 6 is represented in two ways;

- (i) the well established  $V_{T0}$  and  $r_T$  tangent used for rating purposes and
- (ii) a set of constants A, B, C, and D forming the coefficients of the representative equation for  $V_F$  in terms of  $I_F$  given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given in this report for both hot and cold characteristics. The resulting values for  $V_F$  agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	150°C Coefficients
A	0.6303658	0.2906466
B	$3.745470 \times 10^{-2}$	$5.054005 \times 10^{-2}$
C	$4.279123 \times 10^{-5}$	$3.953989 \times 10^{-5}$
D	$1.319665 \times 10^{-2}$	$1.785807 \times 10^{-2}$

**Curves**

Figure 1 – Forward characteristics of limit device

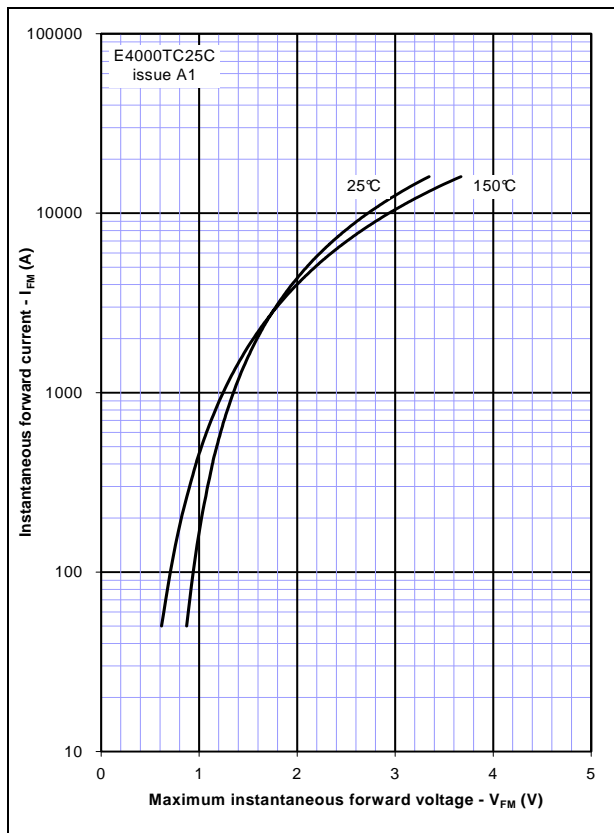


Figure 2 – Maximum forward recovery voltage

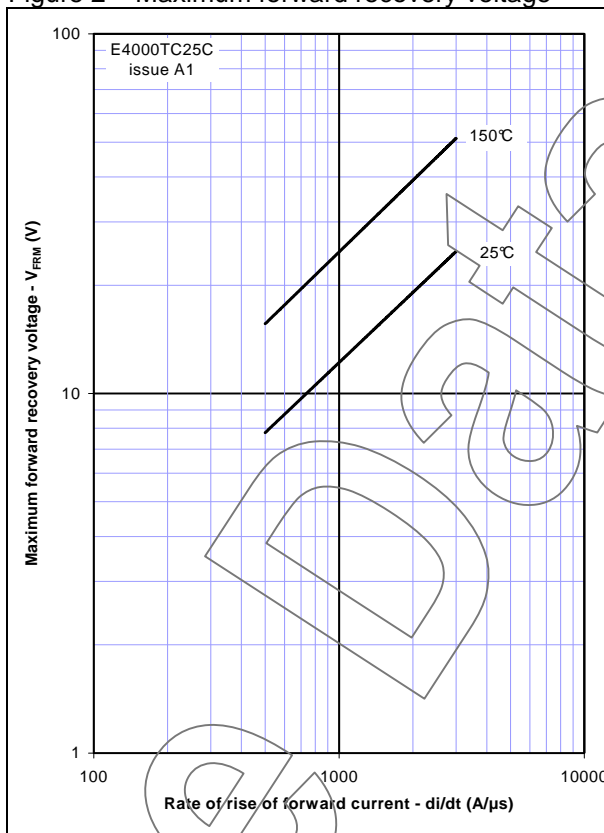


Figure 3 - Recovered charge,  $Q_{rr}$

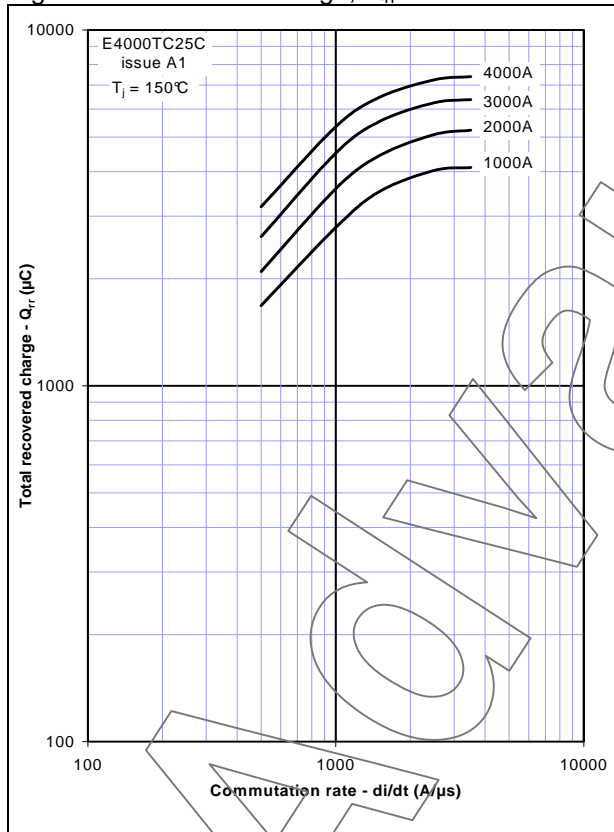


Figure 4 - Recovered charge,  $Q_{ra}$  (50% chord)

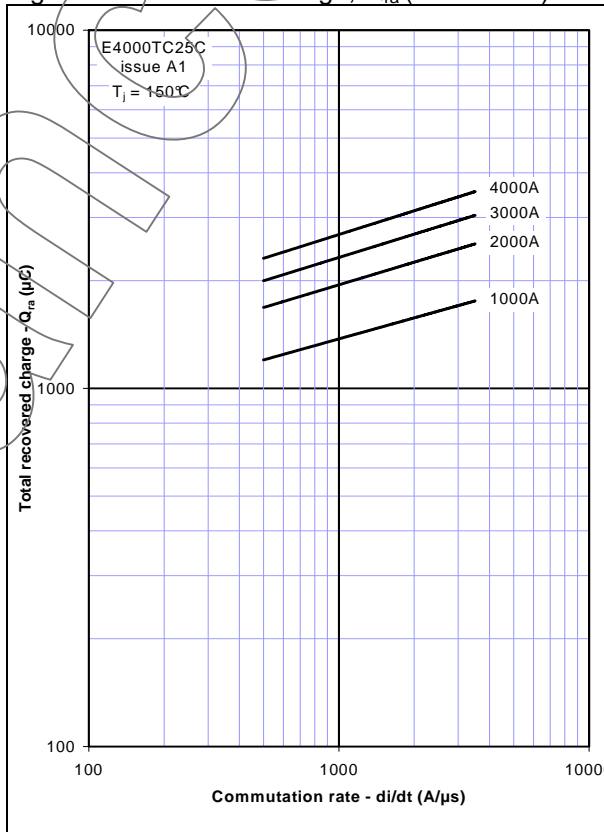


Figure 5 - Maximum reverse current,  $I_{rm}$

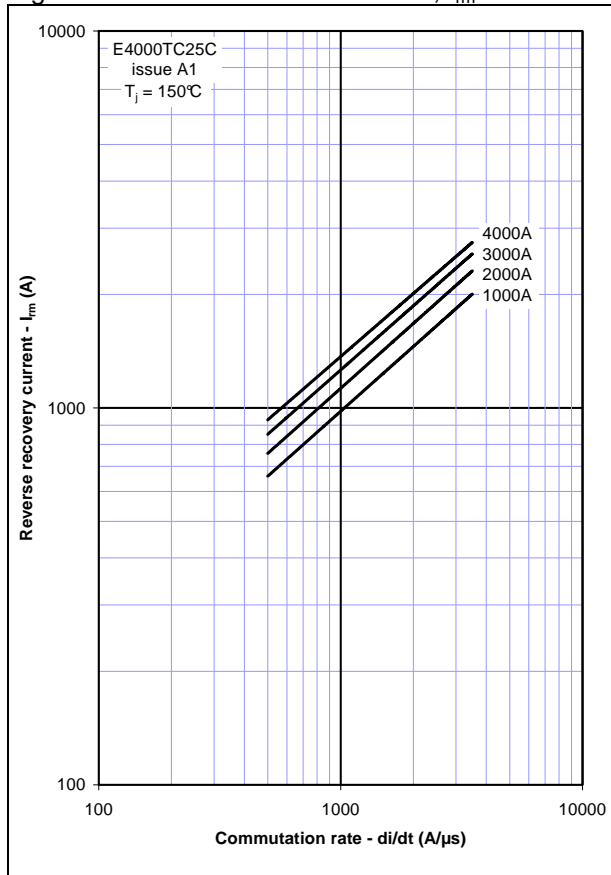


Figure 6 - Maximum recovery time,  $t_{rr}$  (50% chord)

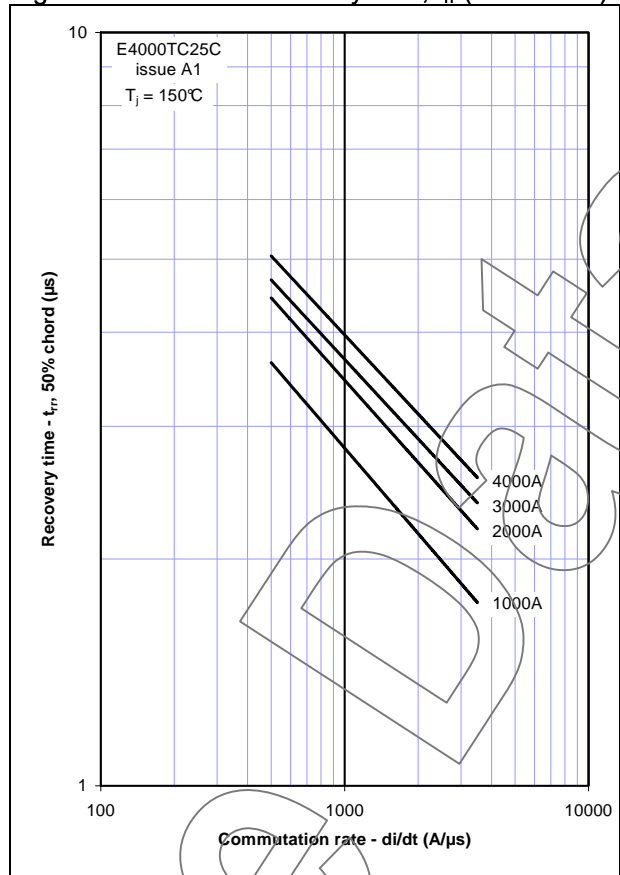


Figure 7 - Reverse recovery energy per pulse

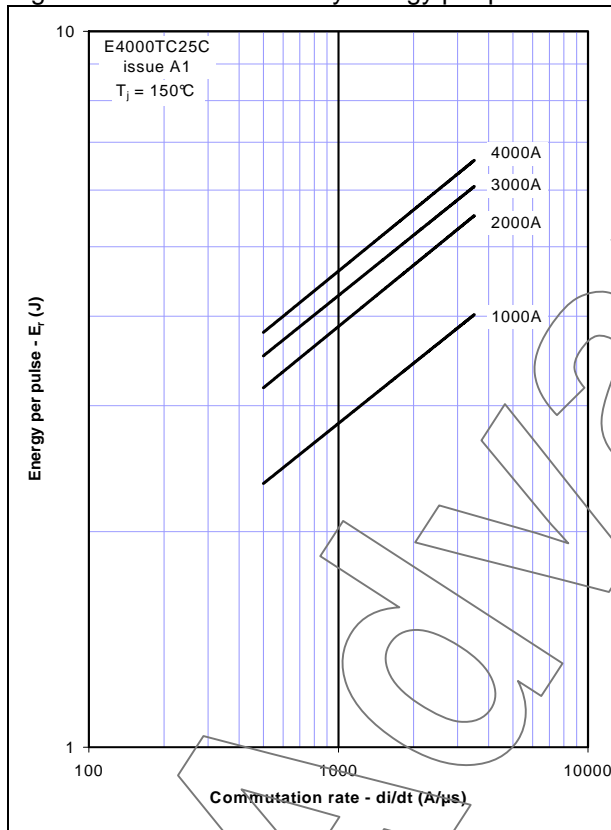


Figure 8 - Sine wave energy per pulse

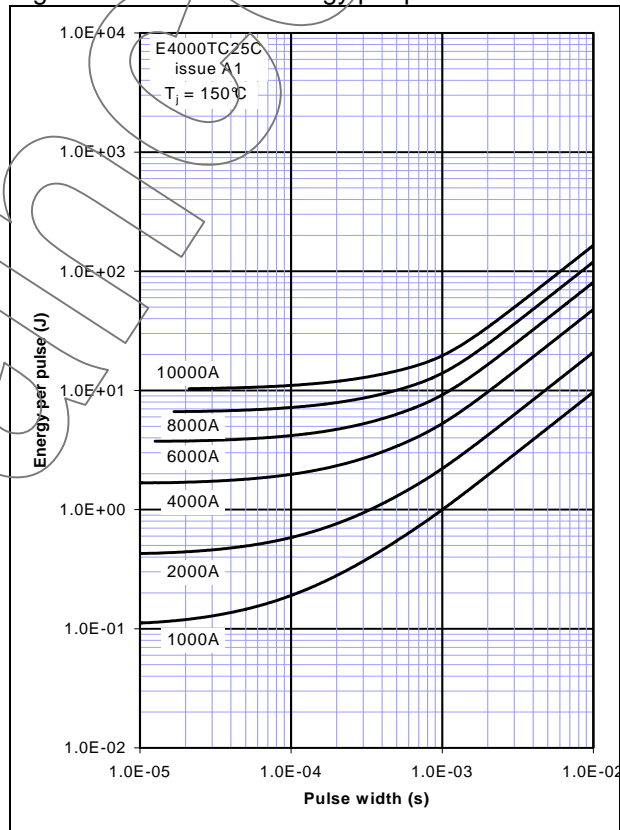


Figure 9 - Sine wave frequency vs. pulse width

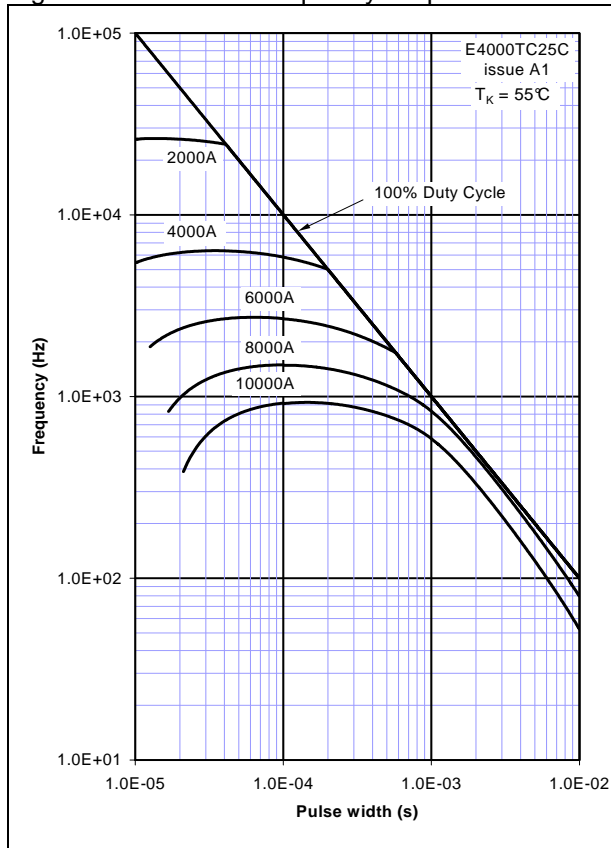


Figure 10 - Sine wave frequency vs. pulse width

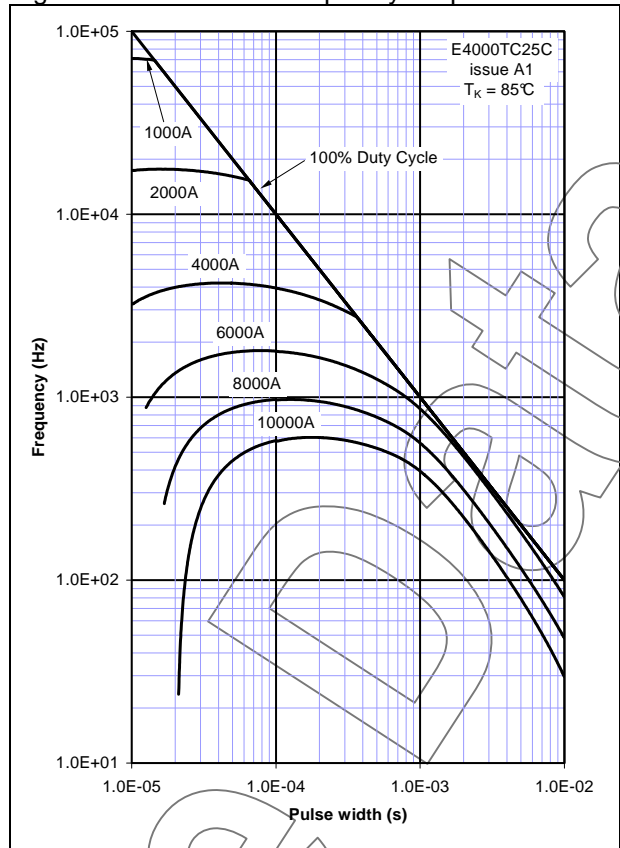


Figure 11 - Square wave energy per pulse

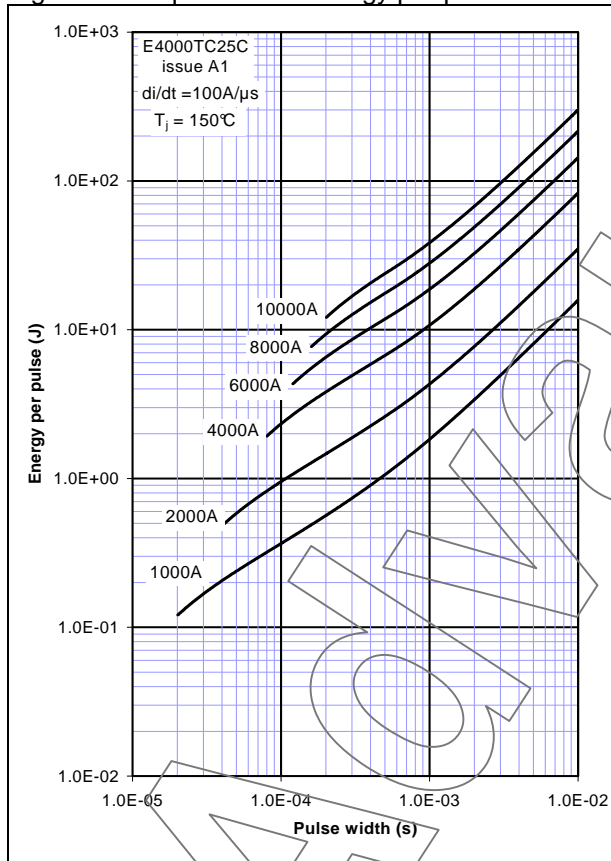


Figure 12 - Square wave energy per pulse

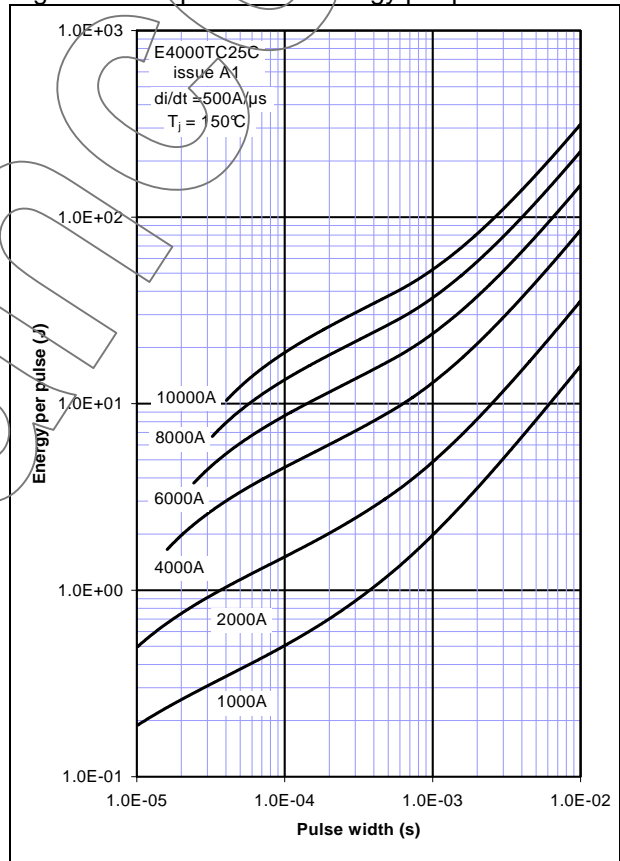


Figure 13 - Square wave frequency vs pulse width

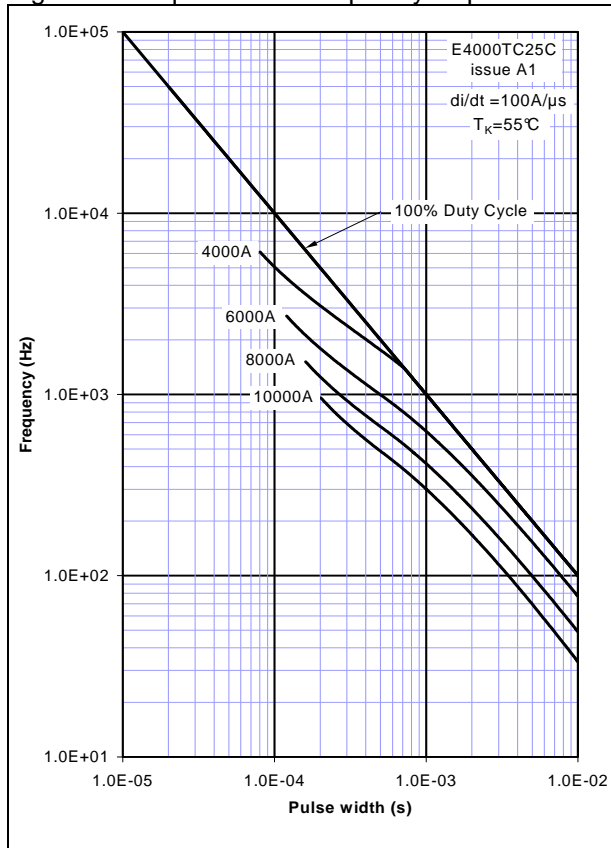


Figure 14 - Square wave frequency vs pulse width

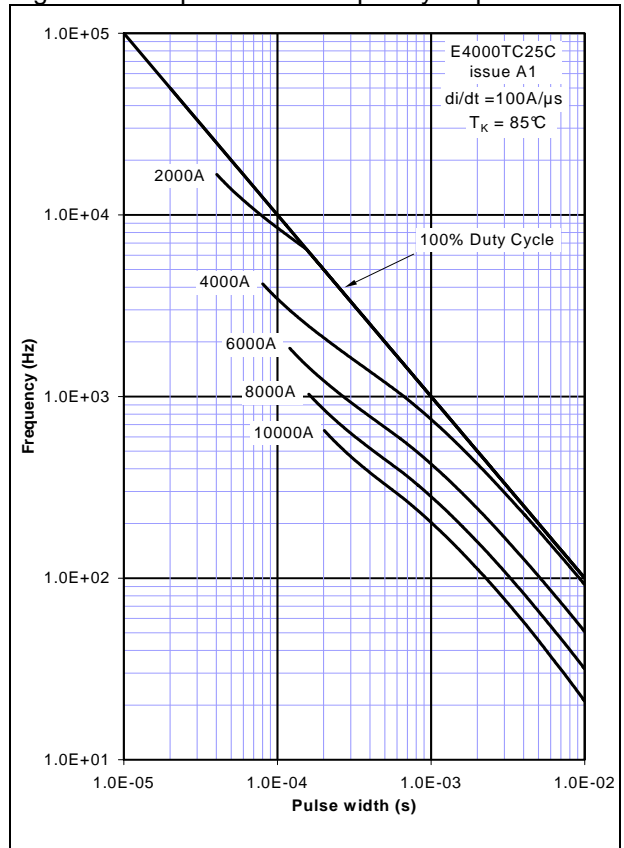


Figure 15 - Square wave frequency vs pulse width

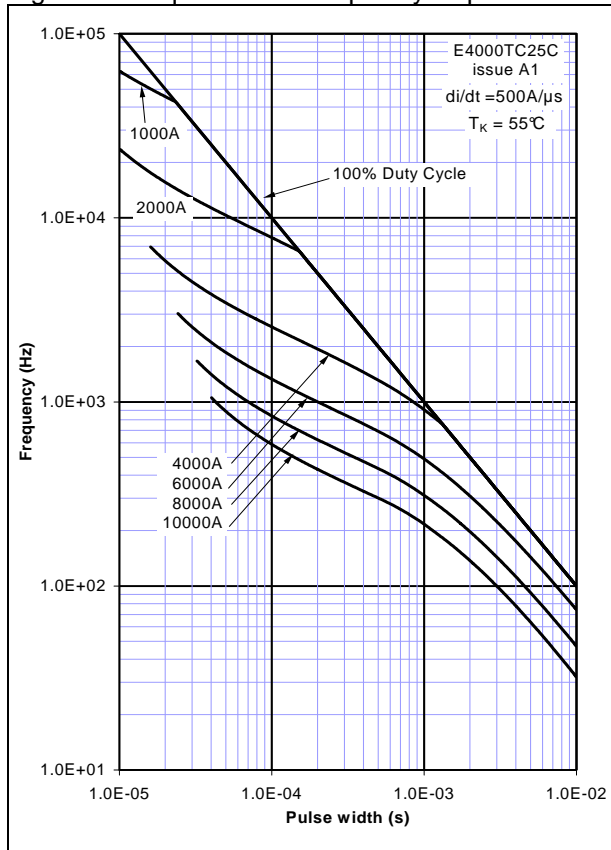


Figure 16 - Square wave frequency vs pulse width

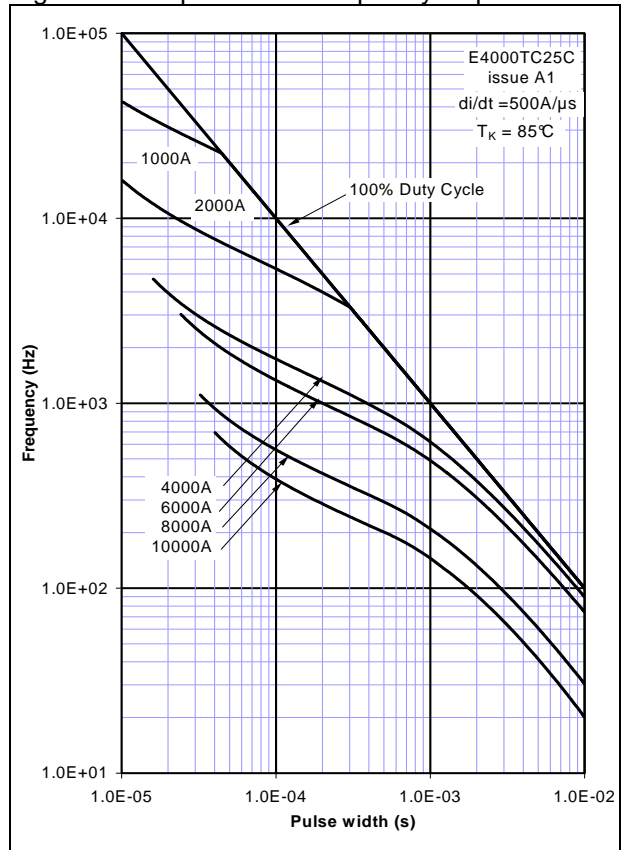


Figure 17 – Safe operating area

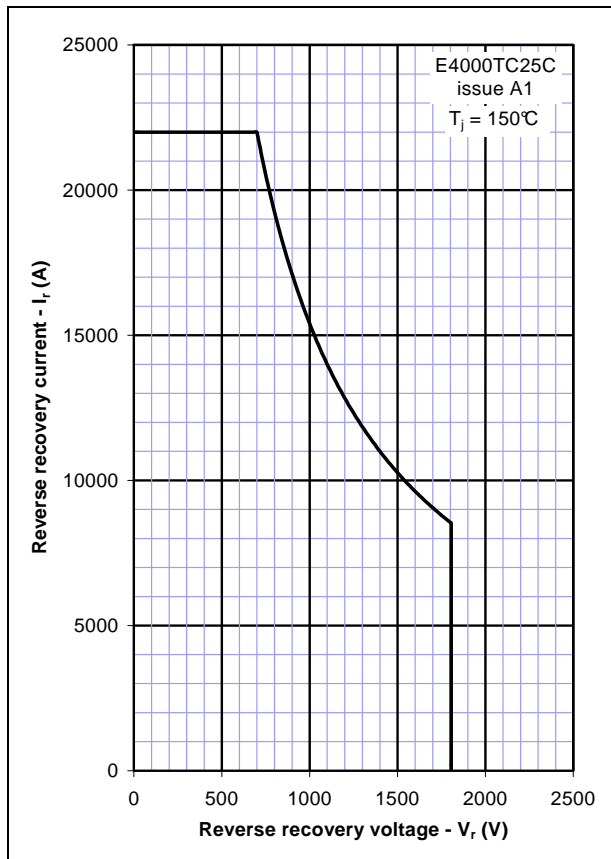


Figure 18 – Transient thermal impedance

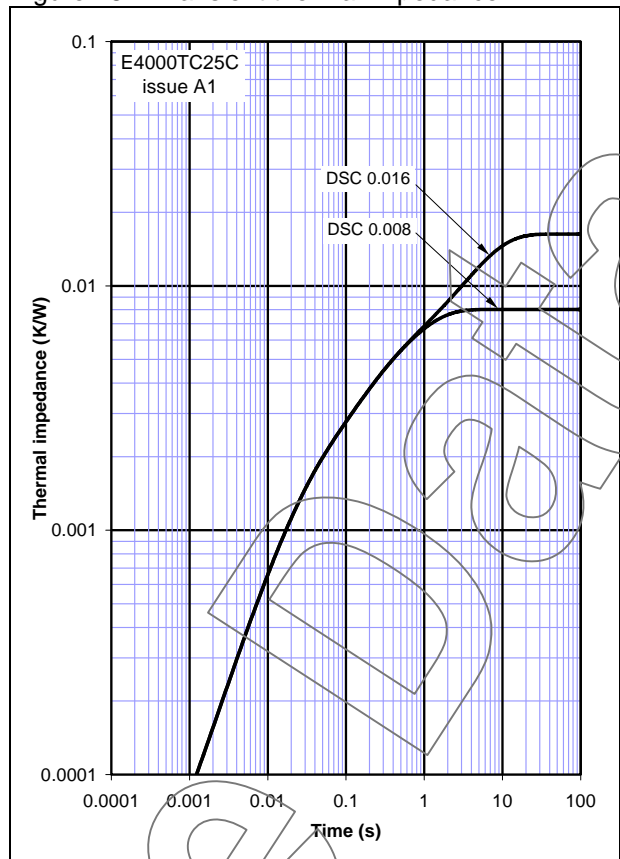
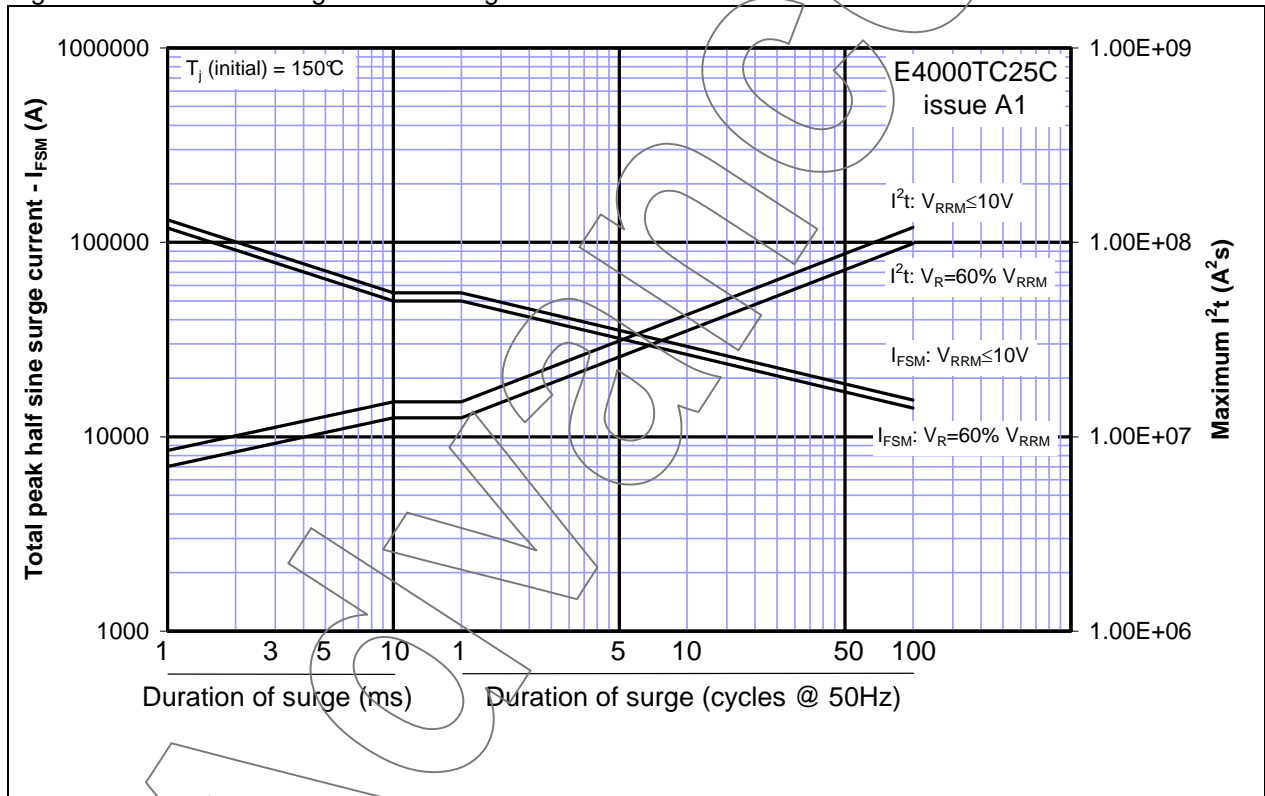
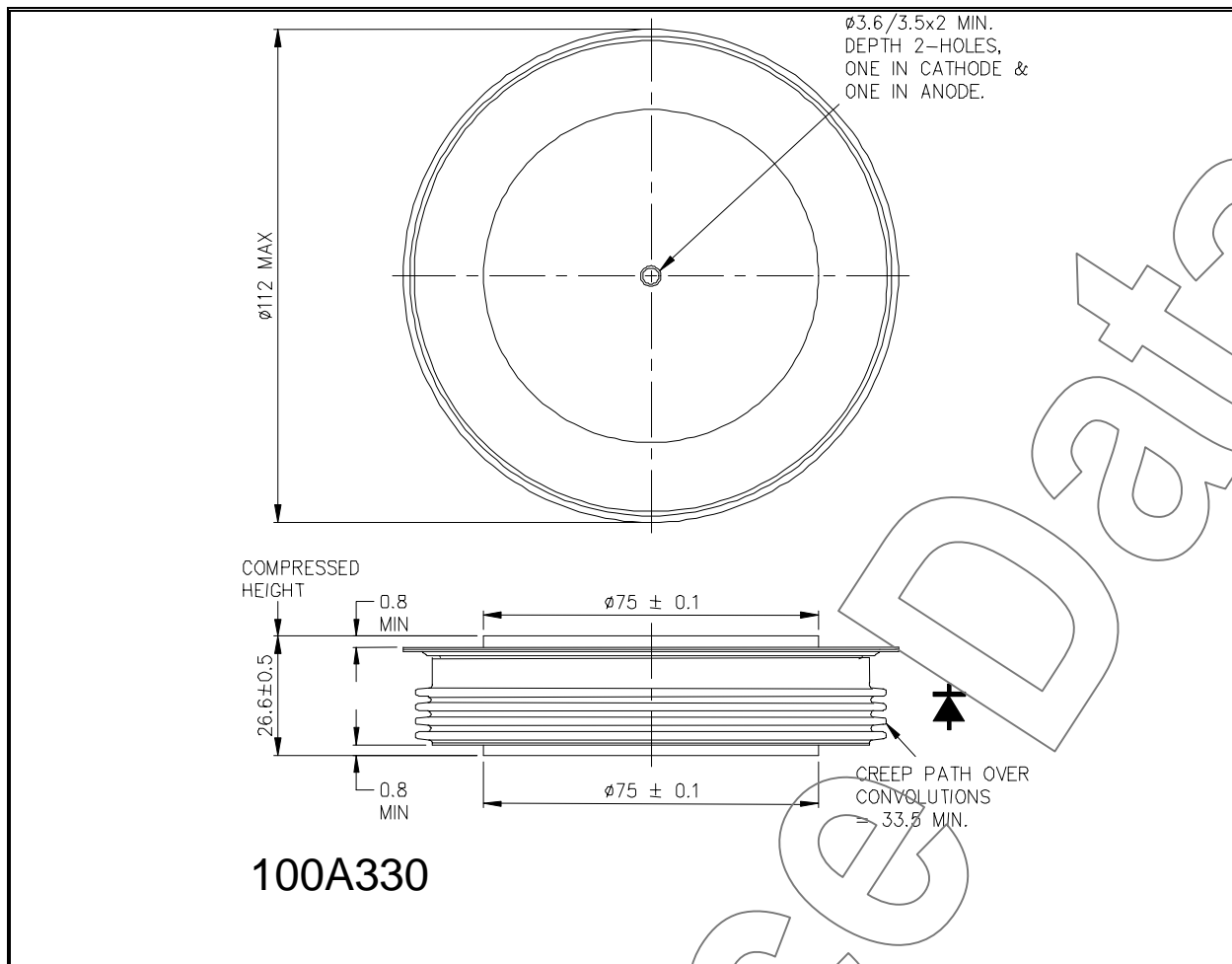


Figure 19 – Maximum surge and  $I^2t$  ratings



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<b>E4000</b>	<b>TC</b>	<b>25</b>	<b>C</b>
Fixed Type Code	Fixed outline code	Fixed voltage code $V_{RRM}/100$ 25	Fixed code, product series

Order code: E4000TC25C – 2500V  $V_{RRM}$ , 26mm clamp height capsule.

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